

Uniform Through-Mask Gold Plating Using the Solstice® GoldPro™ Reactor

You will find high-speed plating in a gold sulfite bath is sensitive to localized flow vectors due to the relatively slow diffusion rate of gold complex ions. As a result, a sub-optimal electrolyte flow profile results in a non-flat plated feature shape. To overcome this issue, most immersion and fountain plating systems require very low plating rates.

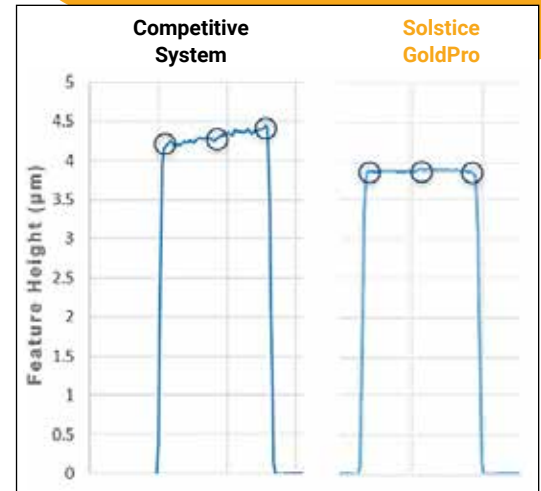
Our proprietary Solstice® GoldPro™ reactor generates randomized fluid vectors at the diffusion layer of the wafer. This ensures that the diffusion layer is as thin as practical, and that fluid motion remains directionless. Ultimately, this results in a flat plated feature profile without sacrificing plating rate.

Applications

- Bond pad for microLEDs
- VCSEL p- and n-contact plating
- Gold bump
- BAW and SAW filters
- Air-bridge
- And more...



The single-wafer processing Solstice Platform is available with 8, 4, 3 or 2 chambers in customizable configurations, depending on the applications you require.



Performance comparison of GoldPro and competitive system on through-mask gold plating.

Features

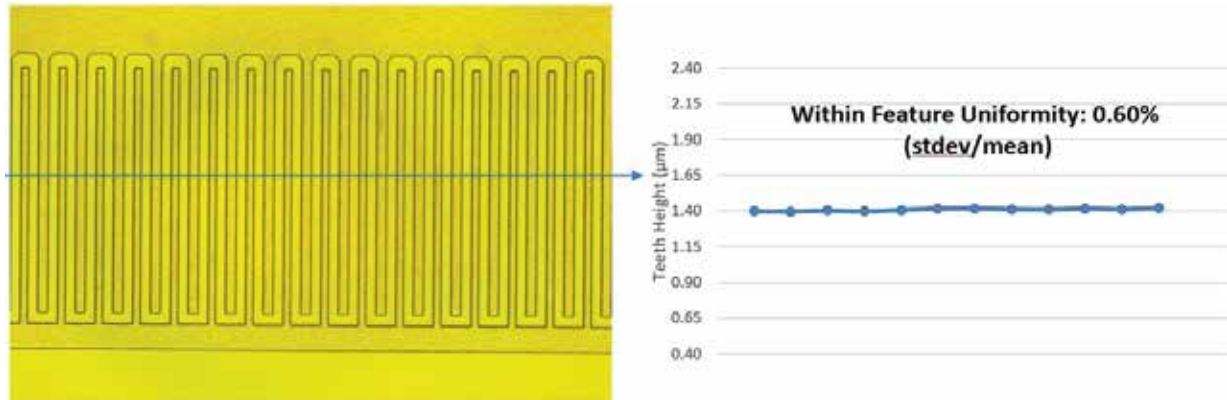
- Randomized fluid vectoring
- Adjustable diffuser
- Dissolved oxygen control
- Dry-contact, low-maintenance plating rotor
- Customized seal reach
- Continuously filtered chemistry loop
- Optional carbon filtration
- Levitronix® pump with LeviFlow™

Benefits

- High plating rate and high uniformity
- Extremely uniform field profile
- Maximized bath life
- Seal reach aligns to existing integration
- Continuously cleaner chemistry
- Precise, consistent flow rate control

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Within-Feature Uniformity (WIF) on SAW Filter



Example of Solstice's WIF uniformity on through-mask gold plating of a surface acoustic wave (SAW) filter.

Technical Data

Wafer Sizes	75-200mm	Configurable to non-standard sizes, e.g., 160mm
Wafer Thickness	150µm to >6mm	
Wafer Materials	Silicon GaAs GaN on Si, GaN on Sapphire Sapphire Transparent substrates and more	
Flow Rate	30-60 lpm	Dependent on wafer size
Plating Rate	Up to 1µm/minute	Dependent on chemistry
Within-Wafer Uniformity	<3% (range 2*mean)	
Within-Feature Uniformity	<3% [(max-min) / (max+min)]	
Wafer-to-Wafer Uniformity	1% (mean-to-mean)	
Roughness	<2kÅ	